OKI SEMICONDUCTOR

Dear customers,

About the change in the name such as "Oki Electric Industry Co. Ltd." and "OKI" in documents to OKI Semiconductor Co., Ltd.

The semiconductor business of Oki Electric Industry Co., Ltd. was succeeded to OKI Semiconductor Co., Ltd. on October 1, 2008. Therefore, please accept that although the terms and marks of "Oki Electric Industry Co., Ltd.", “Oki Electric”, and "OKI" remain in the documents, they all have been changed to "OKI Semiconductor Co., Ltd.". It is a change of the company name, the company trademark, and the logo, etc. , and NOT a content change in documents.

October 1, 2008
OKI Semiconductor Co., Ltd.

OKI SEMICONDUCTOR CO., LTD.

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Discontinued Product

FEDR27V3202E-01-01

OKI Semiconductor

This version : Jul. 2000
Previous version: ----------

MR27V3202E

2,097,152–Word × 16–Bit or 4,194,304–Word × 8–Bit One Time PROM

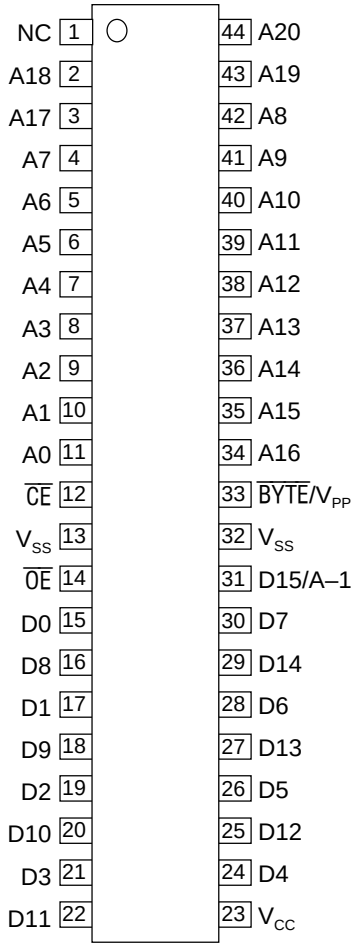
GENERAL DESCRIPTION

The MR27V3202E is a 32 Mbit electrically One Time Programmable Read-Only Memory that can be electrically switched between 2,097,152-word × 16-bit and 4,194,304-word × 8-bit by the state of the $\overline{\text{BYTE}}$ pin. The MR27V3202E supports high speed asynchronous read operation using a single 3.3V power supply.

FEATURES

· 2097,152-word × 16-bit/4,194,304-word × 8-bit electrically switchable configuration
· +3.3 V power supply
· Access time 90 ns MAX
· Operating current 50 mA MAX
· Standby current 50 µA MAX
· Input/Output TTL compatible
· Tri-state output
· Packages:
44-pin plastic SOP (SOP44-P-600-1.27-K) (Product Name : MR27V3202EMA)
44-pin plastic TSOP (TSOP II 44-P-400-0.80-K) (Product Name : MR27V3202ETP)

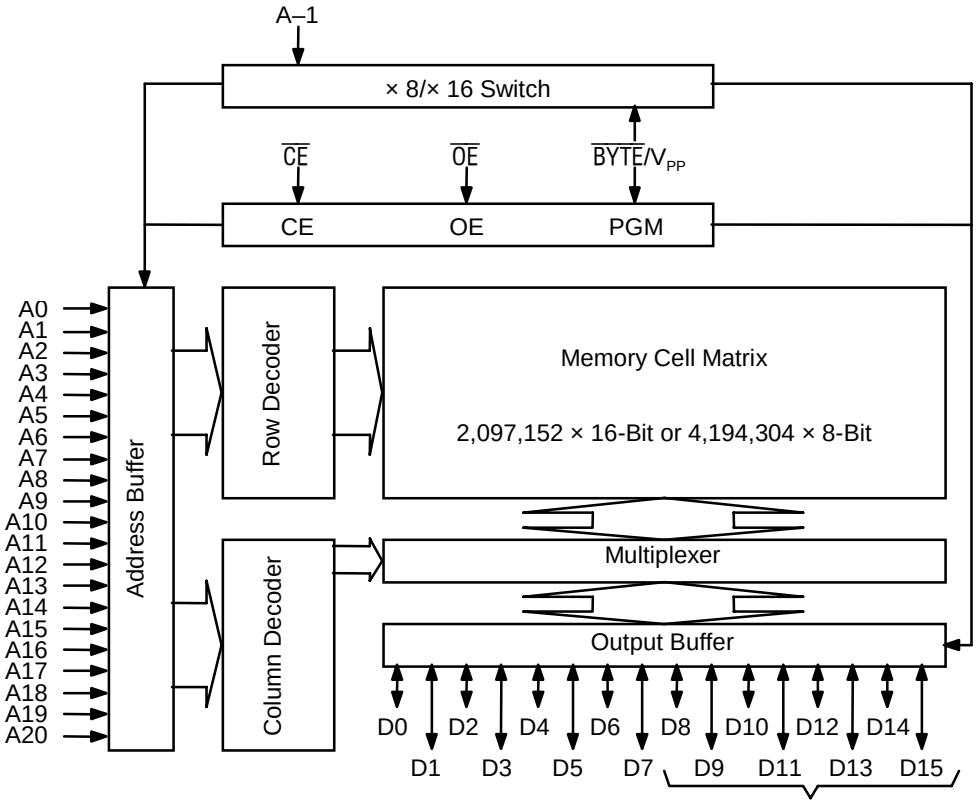
PIN CONFIGURATION (TOP VIEW)



44-pin SOP, TSOP(II)

Pin name	Functions
D15/A–1	Data output/Address input
A0 to A20	Address input
D0 to D14	Data output
$\overline{CE}$	Chip enable
$\overline{OE}$	Output enable
$\overline{BYTE}/V_{PP}$	Mode switch/Program power supply voltage
V_{CC}	Power supply voltage
V_{SS}	GND
NC	Non connection

BLOCK DIAGRAM



In 8-bit output mode, these pins are placed in a high-Z state and pin D15 functions as the A-1 address pin.

FUNCTION TABLE

Mode	$\overline{CE}$	$\overline{OE}$	$\overline{BYTE}/V_{PP}$	V_{CC}	D0 to D7	D8 to D14	D15/A–1
Read (16-Bit)	L	L	H	3.3 V	D_{OUT}		
Read (8-Bit)	L	L	L		D_{OUT}	Hi–Z	L/H
Output disable	L	H	H		Hi–Z		
			L				*
Standby	H	*	H		Hi–Z		
			L				*
Program	L	H	9.75 V	4.0 V	D_{IN}		
Program inhibit	H	H			Hi–Z		
Program verify	H	L			D_{OUT}		

*: Don't Care (H or L)

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Value	Unit
Operating temperature under bias	Ta	—	0 to 70	°C
Storage temperature	Tstg		–55 to 125	°C
Input voltage	V_I	relative to V_{SS}	–0.5 to V_{CC}+0.5	V
Output voltage	V_O		–0.5 to V_{CC}+0.5	V
Power supply voltage	V_{CC}		–0.5 to 5	V
Program power supply voltage	V_{PP}		–0.5 to 11.5	V
Power dissipation per package	P_D	—	1.0	W

RECOMMENDED OPERATING CONDITIONS

(Ta = 0 to 70°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
V_{CC} power supply voltage	V_{CC}	V_{CC} = 3.0 to 3.6 V	3.0	—	3.6	V
V_{PP} power supply voltage	V_{PP}		–0.5	—	V_{CC}+0.5	V
Input “H” level	V_{IH}		2.2	—	V_{CC}+0.5*	V
Input “L” level	V_{IL}		–0.5**	—	0.6	V

Voltage is relative to V_{SS}.

* : Vcc+1.5V(Max.) when pulse width of overshoot is less than 10ns.

** : -1.5V(Min.) when pulse width of undershoot is less than 10ns.

ELECTRICAL CHARACTERISTICS

DC Characteristics

(V_{CC} = 3.3 V ± 0.3 V, Ta = 0 to 70°C)

parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I_{LI}	V_I = 0 to V_{CC}	—	—	10	µA
Output leakage current	I_{LO}	V_O = 0 to V_{CC}	—	—	10	µA
V_{CC} power supply current (Standby)	I_{CCSC}	$\overline{CE}$ = V_{CC}	—	—	50	µA
	I_{CCST}	$\overline{CE}$ = V_{IH}	—	—	1	mA
V_{CC} power supply current (Read)	I_{CCA}	$\overline{CE}$ = V_{IL}, $\overline{OE}$ = V_{IH} tc = 90 ns	—	—	50	mA
V_{PP} power supply current	I_{PP}	V_{PP} = V_{CC}	—	—	10	µA
Input "H" level	V_{IH}	—	2.2	—	V_{CC}+0.5*	V
Input "L" level	V_{IL}	—	–0.5**	—	0.6	V
Output "H" level	V_{OH}	I_{OH} = –2 mA	2.4	—	—	V
Output "L" level	V_{OL}	I_{OL} = 4 mA	—	—	0.4	V

Voltage is relative to V_{SS}.

* : Vcc+1.5V(Max.) when pulse width of overshoot is less than 10ns.

** : -1.5V(Min.) when pulse width of undershoot is less than 10ns.

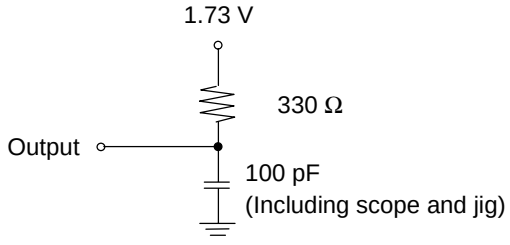
AC Characteristics

(V_{CC} = 3.3 V ± 0.3 V, Ta = 0 to 70°C)

Parameter	Symbol	Condition	Min.	Max.	Unit
Address cycle time	t_C	—	90	—	ns
Address access time	t_{ACC}	$\overline{CE}$ = $\overline{OE}$ = V_{IL}	—	90	ns
$\overline{CE}$ access time	t_{CE}	$\overline{OE}$ = V_{IL}	—	90	ns
$\overline{OE}$ access time	t_{OE}	$\overline{CE}$ = V_{IL}	—	45	ns
Output disable time	t_{CHZ}	$\overline{OE}$ = V_{IL}	0	30	ns
	t_{OHZ}	$\overline{CE}$ = V_{IL}	0	25	ns
Output hold time	t_{OH}	$\overline{CE}$ = $\overline{OE}$ = V_{IL}	0	—	ns

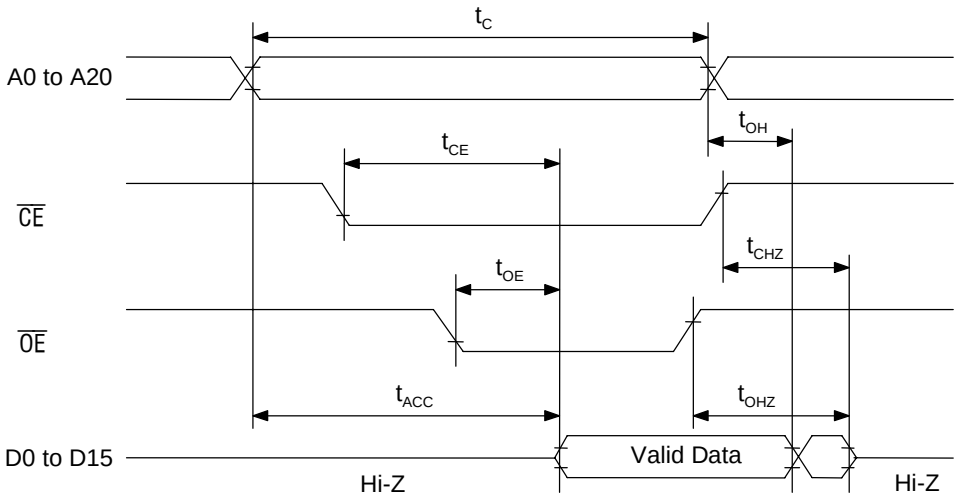
Measurement conditions

Input signal level---------- 0 V/3 V
Input timing reference level ---------- 0.8 V/2.0 V
Output load ---------- 100 pF
Output timing reference level---------- 0.8 V/2.0 V

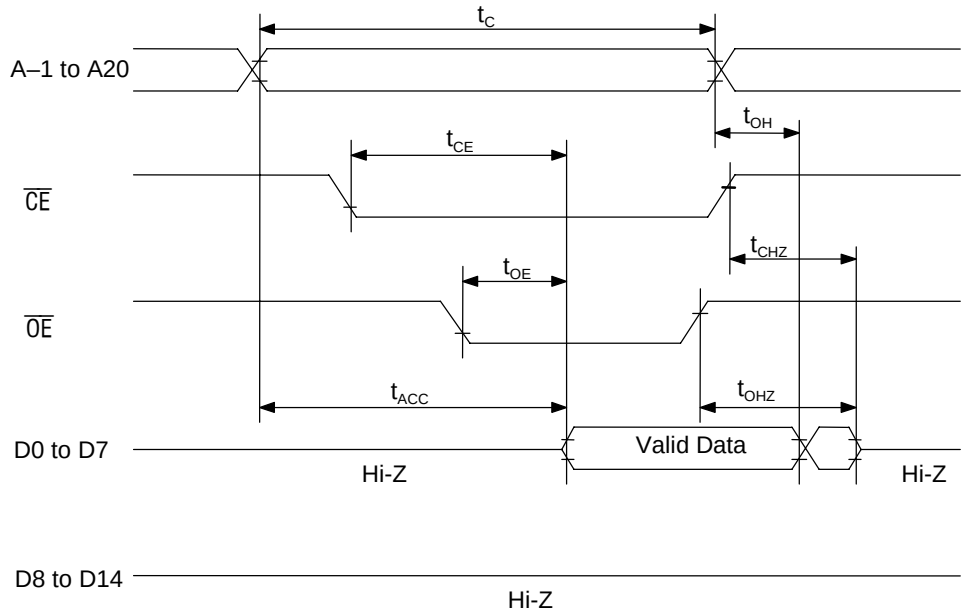


Timing Chart (Read Cycle)

16-Bit Read Mode ($\overline{BYTE}$ = V_{IH})



8-Bit Read Mode ($\overline{BYTE}$ = V_{IL})



ELECTRICAL CHARACTERISTICS (PROGRAMMING OPERATION)

DC Characteristics

(Ta = 25°C ± 5°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I_{LI}	$V_I = V_{CC}+0.5$ V	—	—	10	µA
V_{PP} power supply current (Program)	I_{PP2}	$\overline{CE} = V_{IL}$	—	—	50	mA
V_{CC} power supply current	I_{CC}	—	—	—	50	mA
Input "H" level	V_{IH}	—	3.0	—	$V_{CC}+0.5$	V
Input "L" level	V_{IL}	—	–0.5	—	0.8	V
Output "H" level	V_{OH}	I_{OH} = –400 µA	2.4	—	—	V
Output "L" level	V_{OL}	I_{OL} = 2.1 mA	—	—	0.45	V
Program voltage	V_{PP}	—	9.5	9.75	10.0	V
V_{CC} power supply voltage	V_{CC}	—	3.9	4.0	4.1	V

Voltage is relative to V_{SS}.

AC Characteristics

(V_{CC} = 4.0 V ± 0.1 V, $\overline{BYTE}/V_{PP}$ = 9.75 V ± 0.25 V, Ta = 25°C ± 5°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Address set-up time	t_{AS}	—	100	—	—	ns
$\overline{OE}$ set-up time	t_{OES}	—	2	—	—	µs
Data set-up time	t_{DS}	—	100	—	—	ns
Address hold time	t_{AH}	—	2	—	—	µs
Data hold time	t_{DH}	—	100	—	—	ns
Output float delay time from $\overline{OE}$	t_{OHZ}	—	0	—	100	ns
V_{PP} voltage set-up time	t_{VS}	—	2	—	—	µs
Program pulse width	t_{PW}	—	9	10	11	µs
Data valid from $\overline{OE}$	t_{OE}	—	—	—	100	ns
Address hold from $\overline{OE}$ high	t_{AOH}	—	0	—	—	ns

Pin Check Function

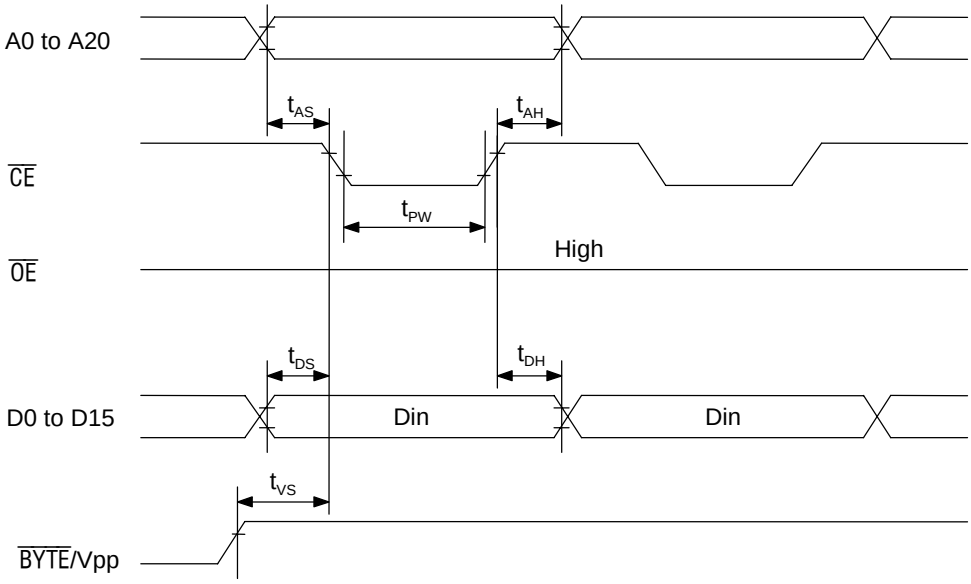
Pin Check Function is to check contact between each device-pin and each socket-lead with EPROM programmer. Setting up address as following condition call the preprogrammed codes on device outputs.

(V_{CC} = 3.3 V ± 0.3 V, $\overline{CE} = V_{IL}$, $\overline{OE} = V_{IL}$, $\overline{BYTE}/V_{PP} = V_{IH}$, Ta = 25°C ± 5°C)

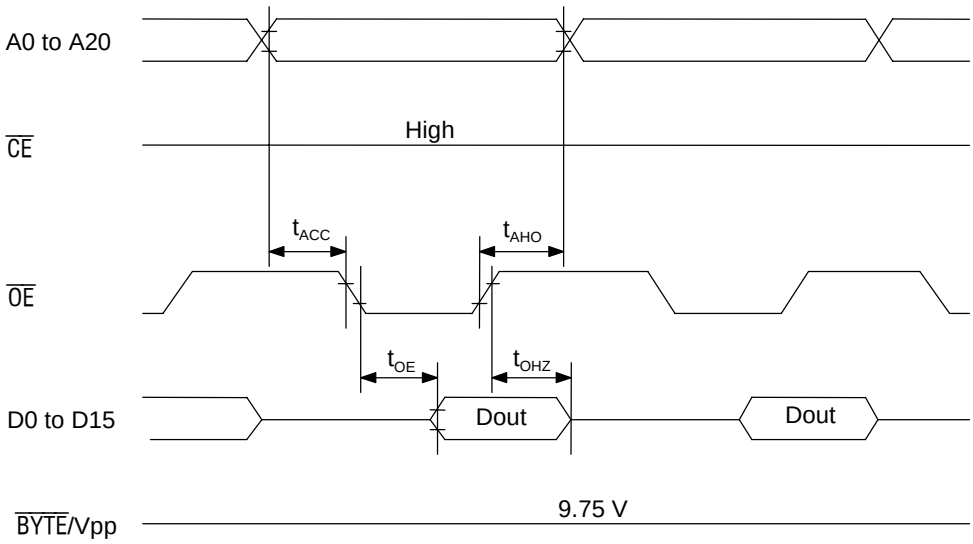
A0	A1	A2	A3	A4	A5	A6	A7	A8	A9	A10	A11	A12	A13	A14	A15	A16	A17	A18	A19	A20	DATA
0	1	0	1	0	1	0	1	0	VH*	0	1	0	1	0	1	0	0	1	1	0	FF00
1	0	1	0	1	0	1	0	1	VH*	1	0	1	0	1	0	1	1	0	0	1	00FF
Other conditions																					FFFF

*: VH = 8 V ± 0.25 V

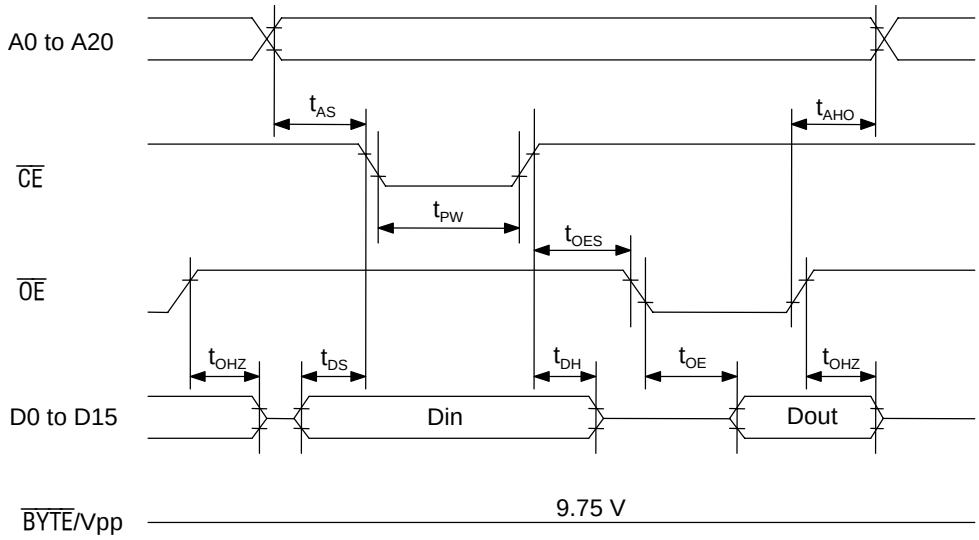
Consecutive Programming Waveforms



Consecutive Program Verify Waveforms



Program and Program Verify Cycle Waveforms

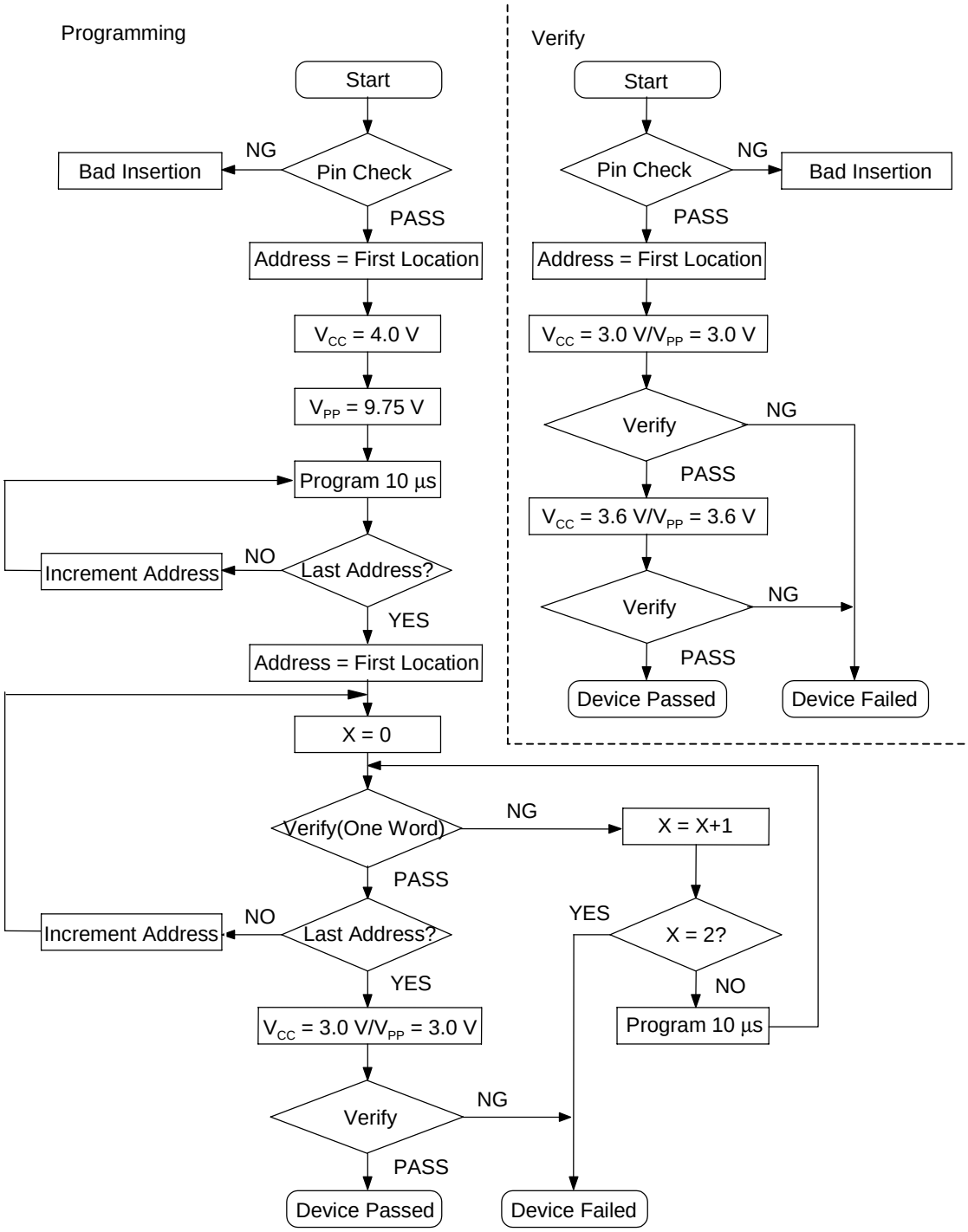


Pin Capacitance

(V_{CC} = 3.3 V, Ta = 25°C, f = 1 MHz)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input	C_{IN1}	V_I = 0 V	—	—	8	pF
$\overline{BYTE}/V_{PP}$	C_{IN2}		—	—	120	
Output	C_{OUT}	V_O = 0 V	—	—	10	

Programming/Verify Flow Chart



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